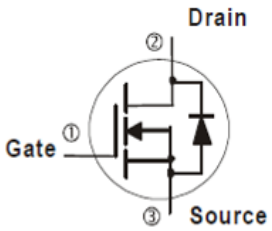
650V N-Channel Super Junction MOSFET

Voltage	**650 V**	**Rdson**	**75mΩ**
Current	**46 A**	**Qg**	**78.5nC**

TO-220AB-L



Feature:

- $R_{DS(ON)\ Max}$, V_{GS}@10V : 75mΩ
- Body diode with fast recovery characteristics
- High Speed Switching and Low $R_{DS(ON)}$
- 100% Avalanche Tested
- 100% Rg Tested
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: TO-220AB-L package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0739 ounces, 2.0948 grams

Application

- PFC/LLC/ PSFB of PSU.

Absolute Maximum Ratings (T_A = 25 °C unless otherwise specified)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage @ T_{jmax}		V_{DS}	700	V
Drain-Source Voltage		V_{DS}	650	
Gate-Source Voltage		V_{GS}	±30	
Continuous Drain Current	T_C=25°C	I_D	46	A
	T_C=100°C		29	
Pulsed Drain Current	T_C=25°C	I_{DM}	114	A
Single Pulse Avalanche Energy (Note 6)		E_{AS}	180	mJ
MOSFET dv/dt ruggedness		dv/dt	120	V/ns
Diode dv/dt		dv/dt	70	V/ns
Power Dissipation	T_C=25°C	P_D	388	W
	T_C=100°C		155	
Operating Junction and Storage Temperature Range		T_J,T_{STG}	-55~150	°C

Thermal Characteristics

PARAMETER		SYMBOL	VALUES			UNITS
			MIN.	TYP.	MAX.	
Thermal Resistance	Junction-to-Case (Bottom)	$R_{\theta JC}$	-	0.23	0.32	°C/W
	Junction-to-Ambient (Note 3)	$R_{\theta JA}$	-	30.6	50	

Electrical Characteristics (T_A = 25 °C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V, I_D=250uA	650	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS}, I_D=250uA	3.3	4.0	4.7	
Drain-Source On-State Resistance	$R_{DS(on)}$	V_{GS}=10V, I_D=17A (Note 1)	-	62.3	75	mΩ
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=650V, V_{GS}=0V	-	-	10	uA
Gate-Source Leakage Current	I_{GSS}	V_{GS}=±30V, V_{DS}=0V	-	-	±100	nA
Transfer characteristics	gfs	V_{DS}=20V, I_D=34A	-	36.6	-	S
Dynamic (Note 5)						
Total Gate Charge	Q_g	V_{DS}=400V, I_D=34A, V_{GS}=10V	-	78.5	-	nC
Gate-Source Charge	Q_{gs}		-	22.8	-	
Gate-Drain Charge	Q_{gd}		-	33.6	-	
Input Capacitance	Ciss	V_{DS}=400V, V_{GS}=0V, f=250kHz	-	3507	-	pF
Output Capacitance	Coss		-	49.7	-	
Reverse Transfer Capacitance	Crss		-	6.1	-	
Effective Output Capacitance Energy Related	Co(er)	V_{DS}=0V to 400V, V_{GS}=0V, f=250kHz (Note 4)	-	95	-	
Turn-On Delay Time	$td_{(on)}$	V_{DD}=400V, I_D=34A, V_{GS}=10V, R_G=10Ω (Note 2)	-	44.4	-	ns
Turn-On Rise Time	t_r		-	140.6	-	
Turn-Off Delay Time	$td_{(off)}$		-	71.3	-	
Turn-Off Fall Time	t_f		-	59.2	-	
Gate Resistance	Rg	f=1.0MHz	-	5.9	-	Ω
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_S		-	-	46	A
Diode Forward Voltage	V_{SD}	I_S=17A, V_{GS}=0V	-	0.90	1.5	V
Reverse Recovery Charge	Q_{rr}	I_S=34A di/dt=100A/μs	-	0.97	-	uC
Reverse Recovery Time	T_{rr}		-	144.4	-	ns
Reverse Recovery Current	I_{rrm}		-	12.3	-	A

NOTES :

1. Pulse width≤380us, Duty cycle≤2%.
2. Essentially independent of operating temperature typical characteristics.
3. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance.
4. $C_{o(er)}$ is a capacitance that gives the same stored energy as Coss while V_{DS} is rising from 0V to 400V.
5. Guaranteed by design, not subject to production testing.
6. E_{AS} is calculated based on the condition of L = 10 mH, I_{AS} = 6 A, V_{DD} = 50 V, V_{GS} = 10 V and 100% test by L=0.1mH. Ias= 7.5A in mass production.

TYPICAL CHARACTERISTIC CURVES

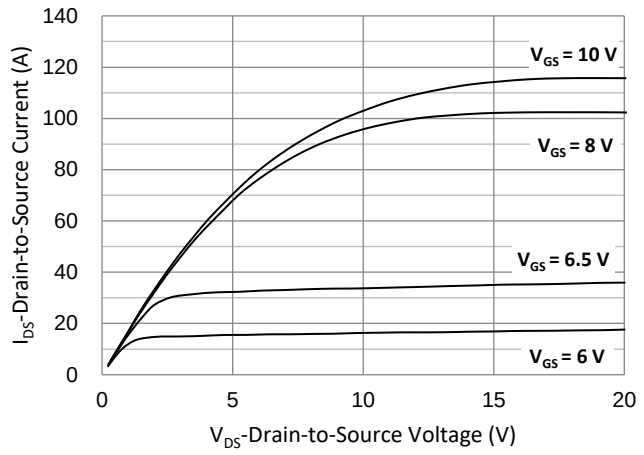


Fig.1 Output Characteristics

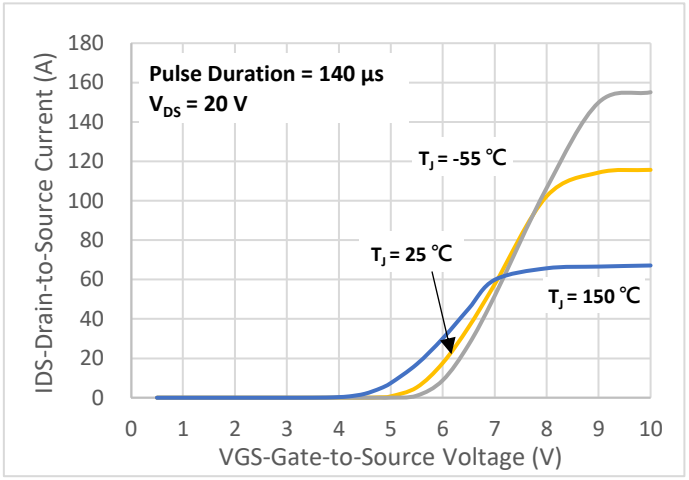


Fig.2 Transfer Characteristics

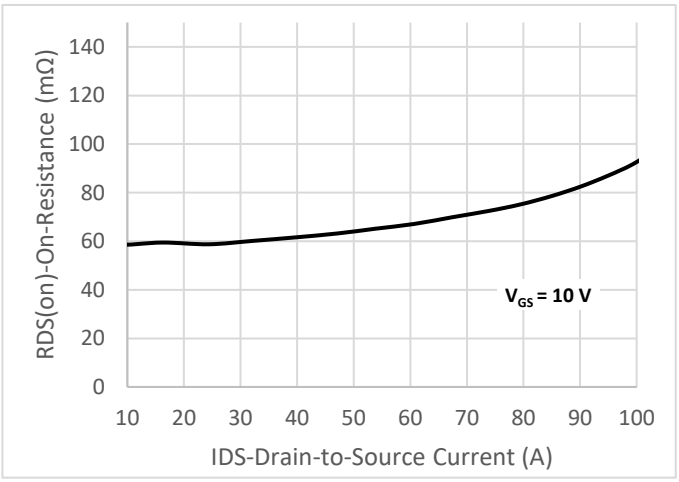


Fig.3 On-Resistance vs. Drain Current

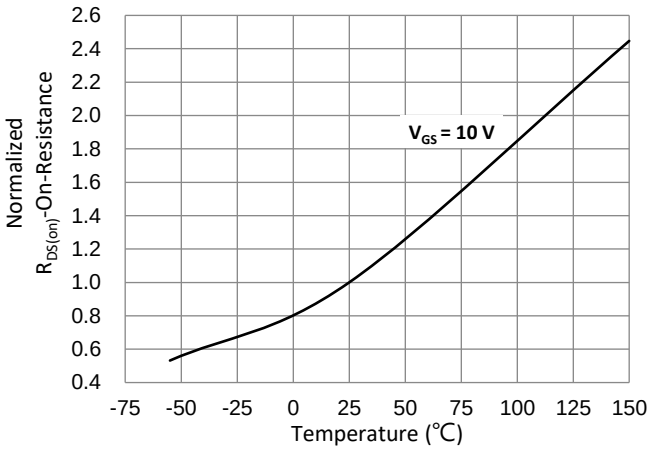


Fig.4 On-Resistance vs. Junction Temperature

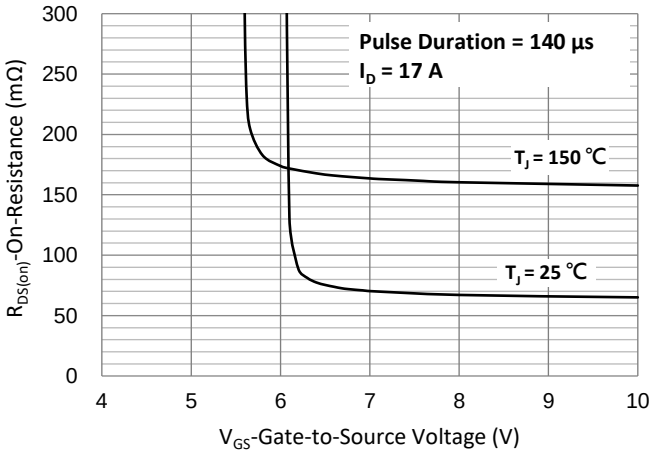


Fig.5 Capacitance vs. Drain-Source Voltage

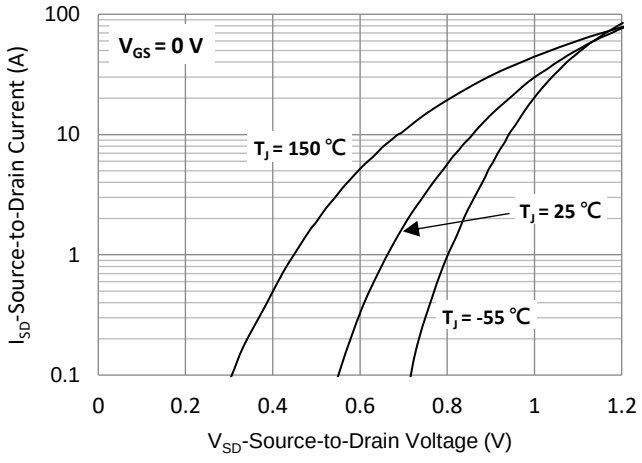


Fig.6 Source-Drain Diode Forward Voltage

TYPICAL CHARACTERISTIC CURVES

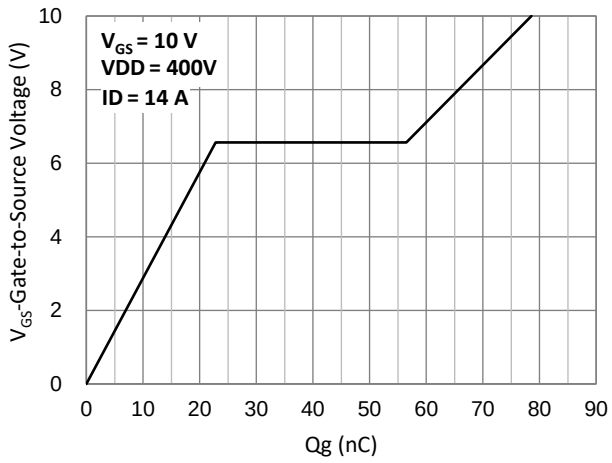


Fig.7 Gate-Charge Characteristics

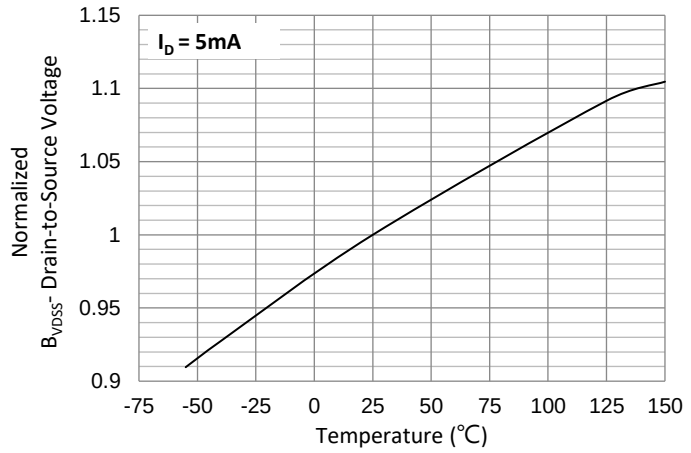


Fig.8 Breakdown Voltage Variation vs. Temperature

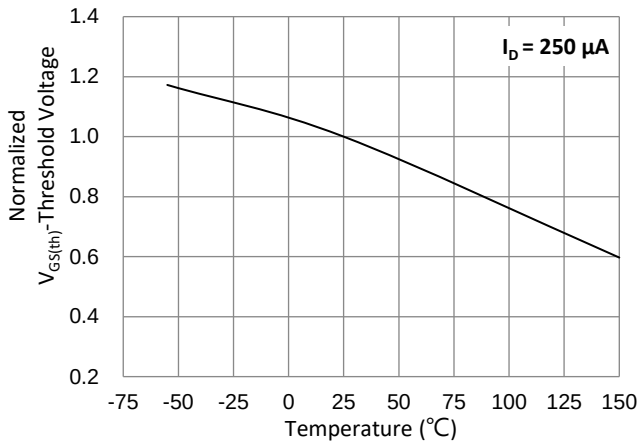


Fig.9 Threshold Voltage Variation with Temperature

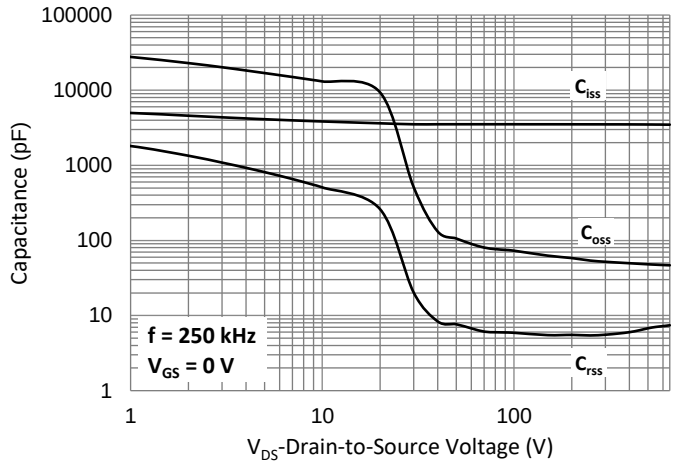


Fig.10 Drain Current vs. Case Temperature

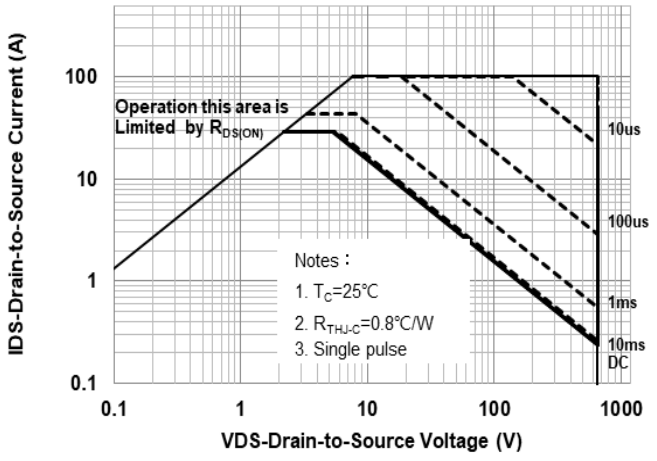


Fig.11 Maximum Safe Operating Area

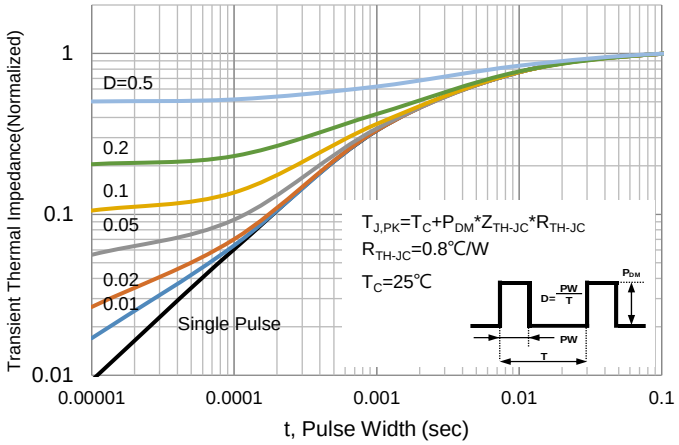


Fig.12 Normalized Transient Thermal Impedance

TYPICAL CHARACTERISTIC CURVES

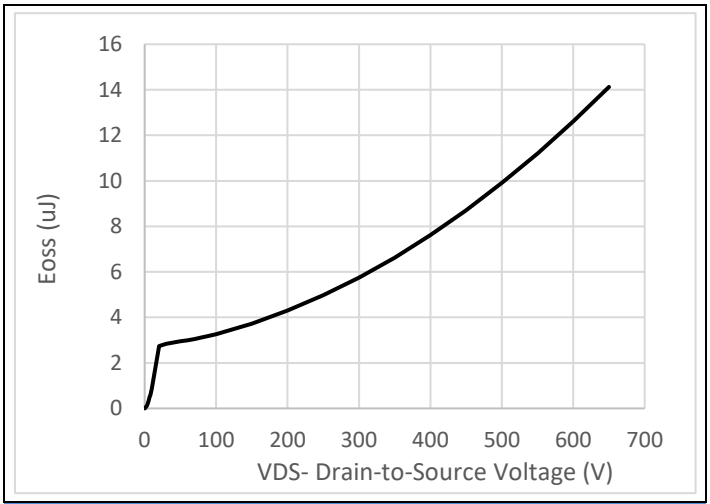


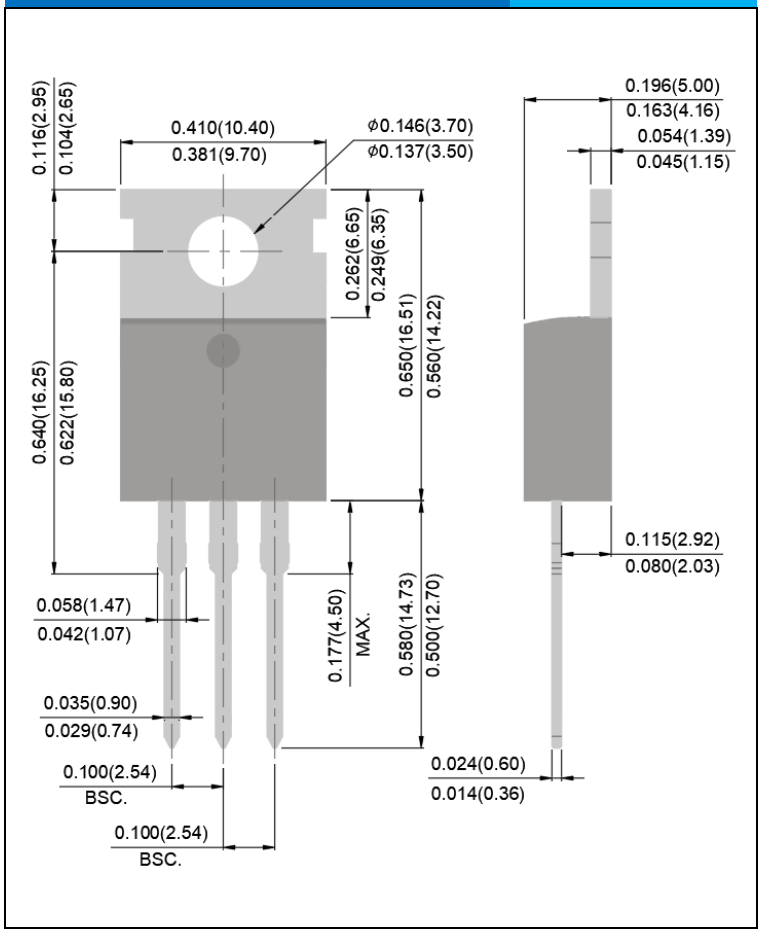
Fig.13 Typ. Coss Stored Energy

Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJMP080N65FR2	TO-220AB-L	50pcs / Tube	080N65FR2

Packaging Information

TO-220AB-L Dimension Unit: inch(mm)



Marking Diagram

PJ
080N65FR2
YWLL x

Y = Year Code
W = Week Code (A~Z)
LL = Lot Code (00~99)
x = Production Line Code

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